

# 4 PIN DIP PHOTOTRANSISTOR PHOTOCOUP EL816 Series



#### Features:

- Compliance Halogens Free (Only copper leadframe) (Br < 900 ppm, Cl < 900 ppm, Br+Cl < 1500 ppm)
- Current transfer ratio (CTR: 50~600% at  $I_F = 5mA$ ,  $V_{CE} = 5V$ ) (CTR: 62, 220% at  $I_F = 10mA$ ,  $V_{CE} = 5V$ )
- (CTR: 63~320% at I<sub>F</sub> = 10mA, V<sub>CE</sub> = 5V) • High isolation voltage between input and output (Viso=5000Vrms)
- Creepage distance > 7.62mm
- Operating temperature up to +110°C
- Compact small outline package
- The product itself will remain within RoHS compliant version
- Compliance with EU REACH
- UL and cUL approved(No. E214129)
- VDE approved (No. 132249)
- SEMKÖ approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CQC approved

## Description

The EL816 series of devices each consist of an infrared emitting diodes,

optically coupled to a phototransistor detector.

They are packaged in a 4-pin DIP package and available in wide-lead spacing and SMD option.

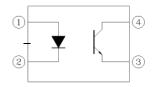
## Applications

- Programmable controllers
- System appliances, measuring instruments
- Telecommunication equipments
- Home appliances, such as fan heaters, etc.
- · Signal transmission between circuits of different potentials and impedances

Schematic

XA

Switch Connector



Pin Configuration

- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector

# Absolute Maximum Ratings (Ta=25°C)

	Parameter	Symbol	Rating	Unit
	Forward current	١ <sub>F</sub>	60	mA
	Peak forward current (1us, pulse)	I <sub>FP</sub>	1	А
Input	Reverse voltage	V <sub>R</sub>	6	V
	Power Dissipation No derating required up to $T_a = 100^{\circ}C$	P <sub>D</sub>	100	mW
	Power dissipation	_	150	mW
	Derating factor (above $T_a = 80^{\circ}C$ )	P <sub>C</sub> —	5.8	mW/°C
Output	Collector current	Ι <sub>C</sub>	50	mA
	Collector-Emitter voltage	V <sub>CEO</sub>	80	V
	Emitter-Collector voltage	V <sub>ECO</sub>	6	V
Total Powe	Total Power Dissipation		200	mW
Isolation V	Isolation Voltage*1		5000	Vrms
Operating	Operating Temperature		-55 to 110	°C
Storage Te	Storage Temperature		-55 to 125	°C
Soldering Temperature* <sup>2</sup>		T <sub>SOL</sub>	260	°C

#### Notes:

\*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 are shorted together, and pins 3, 4 are shorted together. \*2 For 10 seconds

# Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

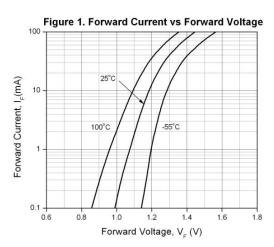
Input							
Parameter		Symbol	Min.	Тур.	Max.	Unit	Condition
Forward Voltage		V <sub>F</sub>	-	1.2	1.4	V	I <sub>F</sub> = 20mA
Reverse Current		I <sub>R</sub>	-	-	10	μA	$V_R = 4V$
Input capacitance		C <sub>in</sub>	-	30	250	pF	V = 0, f = 1kHz
Output							
Param	eter	Symbol	Min	Тур.	Max.	Unit	Condition
Collector-Emitt current	ter dark	I <sub>CEO</sub>	-	-	100	nA	$V_{CE} = 20V, I_F = 0mA$
Collector-Emit breakdown vo		BV <sub>CEO</sub>	80	-	-	V	$I_{\rm C} = 0.1 {\rm mA}$
Emitter-Collec breakdown vo		BV <sub>ECO</sub>	6	-	-	V	I <sub>E</sub> = 0.1mA
Transfer Cha	aracteristic	s					
Param	eter	Symbol	Min	Тур.	Max.	Unit	Condition
	EL816		50	-	600		
					600		
	EL816A		80	-	160		
	EL816A EL816B		80 130	-			
		CTR			160	%	I <sub>F</sub> = 5mA ,V <sub>CE</sub> = 5V
	EL816B	 CTR	130	-	160 260	%	I <sub>F</sub> = 5mA ,V <sub>CE</sub> = 5V
	EL816B EL816C		130 200	-	160 260 400	%	I <sub>F</sub> = 5mA ,V <sub>CE</sub> = 5V
Current	EL816B EL816C EL816D	CTR	130 200 300	-	160 260 400 600	%	I <sub>F</sub> = 5mA ,V <sub>CE</sub> = 5V
Current Transfer ratio	EL816B EL816C EL816D EL816X	CTR	130 200 300 100	- - - -	160 260 400 600 200	%	I <sub>F</sub> = 5mA ,V <sub>CE</sub> = 5V
	EL816B EL816C EL816D EL816X EL816Y		130 200 300 100 150	- - - -	160   260   400   600   200   300	%	$I_F = 5mA$ , $V_{CE} = 5V$ $I_F = 10mA$ , $V_{CE} = 5V$
	EL816B EL816C EL816D EL816X EL816Y EL816I		130   200   300   100   150   63	- - - - - -	160   260   400   600   200   300   125		
	EL816B EL816C EL816D EL816X EL816Y EL816I EL816J	- CTR -	130   200   300   100   150   63   100	- - - - - -	160   260   400   600   200   300   125   200	%	
	EL816B EL816C EL816D EL816X EL816Y EL816I EL816J EL816K		130   200   300   100   150   63   100   160	- - - - - - -	160   260   400   600   200   300   125   200   320		

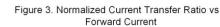
Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
Collector-Emitter saturation voltage	V <sub>CE(sat)</sub>	-	0.1	0.2	V	$I_{F} = 20mA$ , $I_{C} = 1mA$
Isolation resistance	R <sub>IO</sub>	5×10 <sup>10</sup>	-	-	Ω	V <sub>IO</sub> = 500Vdc, 40~60% R.H.
Floating capacitance	C <sub>IO</sub>	-	0.6	1.0	pF	$V_{IO} = 0$ , f = 1MHz
Cut-off frequency	fc	-	80	-	kHz	$V_{CE} = 5V, I_C = 2mA$ $R_L = 100\Omega, -3dB$
Rise time	t <sub>r</sub>	-	4	18	μs	$V_{CE} = 2V, I_{C} = 2mA,$
Fall time	t <sub>f</sub>	-	3	18	μs	$R_L = 100\Omega$

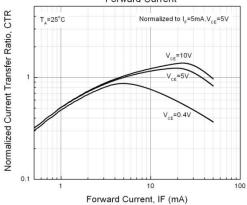
# Transfer Characteristics (T<sub>a</sub>=25°C unless specified otherwise) Continuity

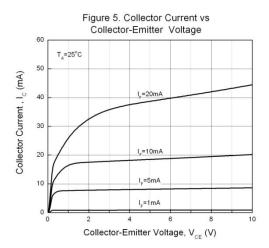
\* Typical values at  $T_a = 25^{\circ}C$ 

# **Typical Electro-Optical Characteristics Curves**









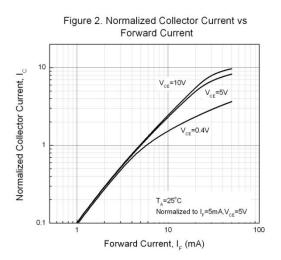
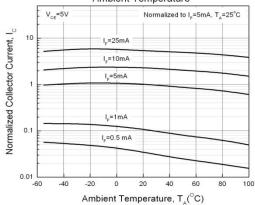
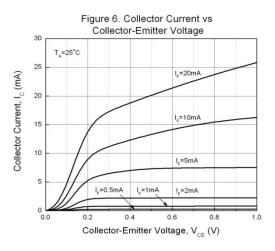
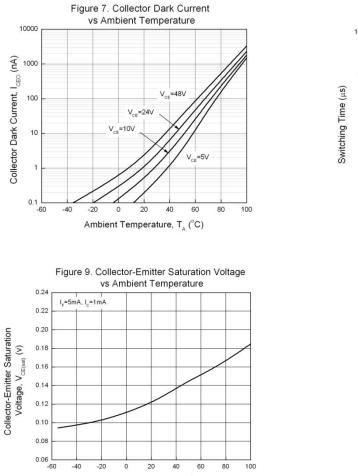


Figure 4. Normalized Collector Current vs Ambient Temperature

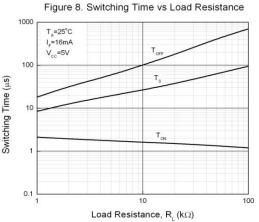






-40 -20 0 20 40 60 80 100

Ambient Temperature (°C)



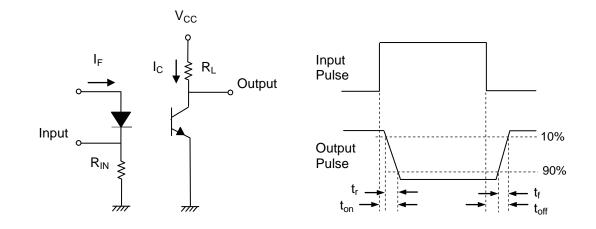


Figure 10. Switching Time Test Circuit & Waveforms

# **Order Information**

Part Number

# EL816X(Y)(Z)-FV

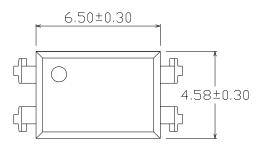
#### Note

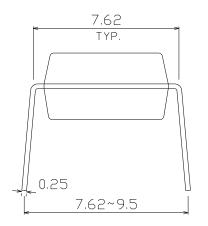
- Х = Lead form option (S1, S2, M or none)
- = CTR Rank (A, B, C, D, X, Y, I, J, K or none) = Tape and reel option (TU, TD or none). Υ
- Ζ
- F = Lead frame option (F: Iron, None: copper)
- V = VDE safety (optional).

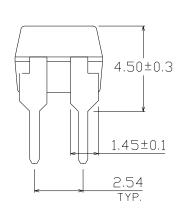
Option	Description	Packing quantity
None	Standard DIP-4	100 units per tube
М	Wide lead bend (0.4 inch spacing)	100 units per tube
S1 (TU)	Surface mount lead form (low profile) + TU tape & reel option	1500 units per reel
S1 (TD)	Surface mount lead form (low profile) + TD tape & reel option	1500 units per reel
S2 (TU)	Surface mount lead form (low profile) + TU tape & reel option	2000 units per reel
S2 (TD)	Surface mount lead form (low profile) + TD tape & reel option	2000 units per reel

# Package Dimension (Dimensions in mm)

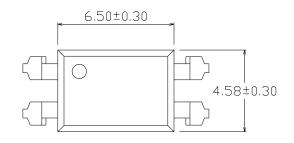
# Standard DIP Type

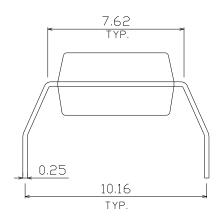


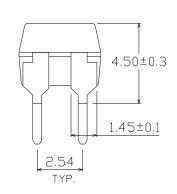




# **Option M Type**

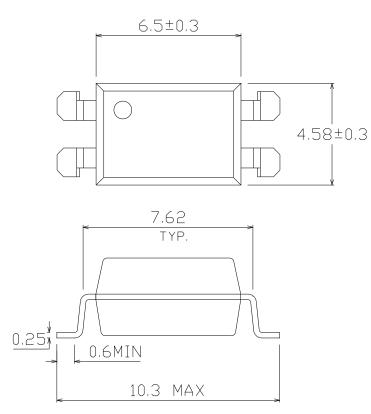


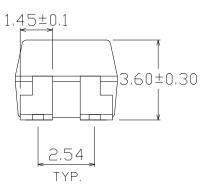




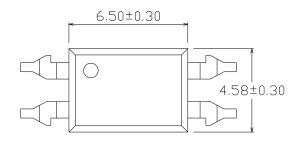
#### DATASHEET 4PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER EL816 series

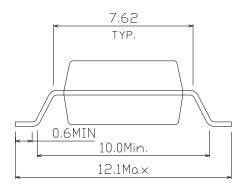
# **Option S1 Type**

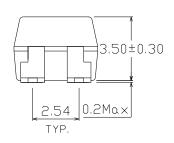




# **Option S2 Type**

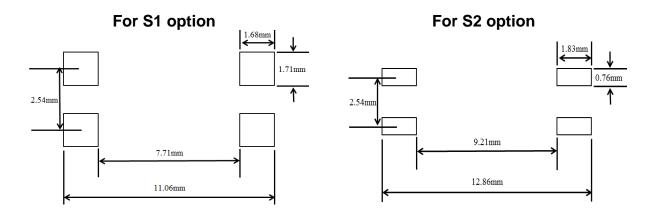




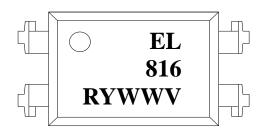


#### DATASHEET 4PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER EL816 series

## Recommended pad layout for surface mount leadform



# **Device Marking**

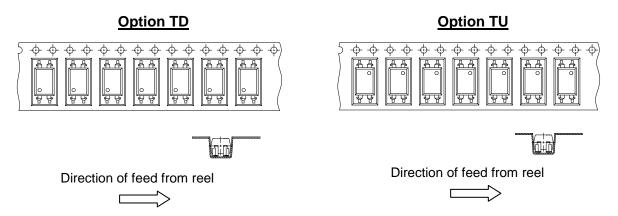




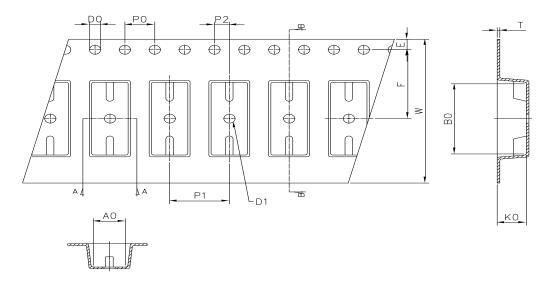
#### Notes

EL	denotes XI BNANG 816
denotes E	Device Number
R	denotes CTR Rank(A, B, C, D, X, Y, I, J, K or none
) Y	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE (optional)

# **Tape & Reel Packing Specifications**



## **Tape dimensions**

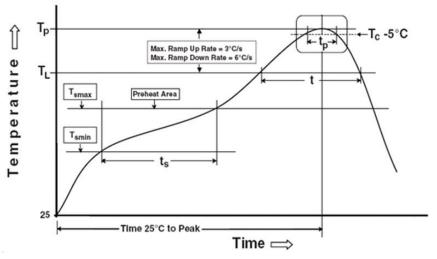


Dimension No.	Ао	Во	Do	D1	E	F
Dimension (mm) S1	4.90±0.1	10.40±0.1	1.5±0.1	1.50±0.1	1.75±0.1	7.50±0.1
Dimension (mm) S2	4.88±0.1	12.55±0.1	1.5±0.1	1.50±0.1	1.75±0.1	11.5±0.1
Dimension No.	Ро	P1	P2	t	w	Ко
Dimension (mm)						
S1	4.00±0.1	8.00±0.	2.00±0.1	0.40±0.1	16.00±0.3	4.60±0.1

# **Precautions for Use**

#### 1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

#### Preheat

150
200°
60-1 3 °C

Liquidus Temperature (T <sub>L</sub> )
Time above Liquidus Temperature (t $_{L}$ )
Peak Temperature (T <sub>P</sub> )
Time within 5 °C of Actual Peak Temperature: $T_P$ - 5°C
Ramp- Down Rate from Peak Temperature
Time 25°C to peak temperature Reflow times

Reference: IPC/JEDEC J-STD-020D

150 °C 200°C 60-120 seconds 3 °C/second max

217 °C 60-100 sec 260°C 30 s 6°C /second max. 8 minutes max. 3 times

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